

PHOTOCOUPLER PS2706-1

AC INPUT RESPONSE DARLINGTON TRANSISTOR SOP MULTI PHOTOCOUPLER SERIES

-NEPOC Series-

DESCRIPTION

The PS2706-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon darlington-connected phototransistor.

This is mounted in a plastic SOP (Small Out-line Package) for high density applications.

This package has shield effect to cut off ambient light.

FEATURES

- · AC input response
- High current transfer ratio (CTR = 2 000 % TYP.)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin (SOP) package
- High-speed switching (t_r, t_f = 200 μs TYP.)
- · Ordering number of taping product: PS2706-1F3, F4
- UL approved: File No. E72422 (S)
- VDE0884 approved (Option)

APPLICATIONS

- Hybrid IC
- · Telephone, Exchange equipment
- FA/OA equipment
- Programmable logic controllers

ORDERING INFORMATION (Solder Contains Lead)

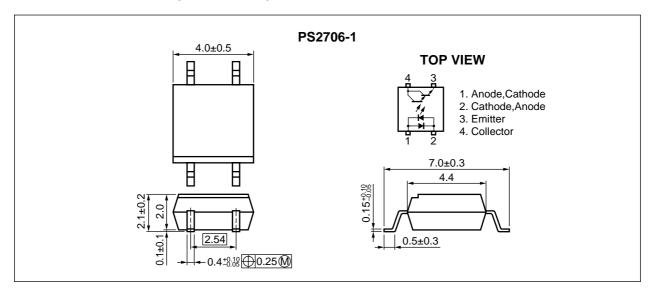
Part Number	Package	Safety Standard Approval
PS2706-1	4-pin SOP	Standard specification products
		UL approved
PS2706-1-V	4-pin SOP	VDE0884 specification products (Option)

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Safety Standard Approval
PS2706-1-A	4-pin SOP	Standard specification products
		UL approved
PS2706-1-V-A	4-pin SOP	VDE0884 specification products (Option)

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

★ PACKAGE DIMENSIONS (in millimeters)



ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	±50	mA
	Power Dissipation Derating	⊿P₀/°C	0.8	mW/°C
	Power Dissipation	Po	80	mW
	Peak Forward Current*1	I FP	±1	Α
Transistor	Collector to Emitter Voltage	Vceo	40	V
	Emitter to Collector Voltage	Veco	6	V
	Collector Current	lc	200	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage*2		BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

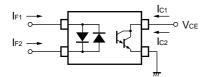
^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

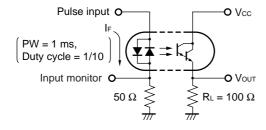
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	$I_F = \pm 5 \text{ mA}$		1.1	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		60		pF
Transistor	Collector to Emitter Dark Current	Iceo	IF = 0 mA, VcE = 40 V			400	nA
Coupled	Current Transfer Ratio (Ic/IF)	CTR	$I_F = \pm 1 \text{ mA}, V_{CE} = 2 \text{ V}$	200	2 000		%
	CTR Ratio*1	CTR1/ CTR2	$I_F = \pm 1$ mA, $V_{CE} = 2$ V	0.3	1.0	3.0	
	Collector Saturation Voltage	VCE (sat)	$I_F = \pm 1 \text{ mA}, I_C = 2 \text{ mA}$			1.0	V
	Isolation Resistance	R _{I-O}	Vi-o = 1 kVpc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time *2	t r	$Vcc = 5 \text{ V}, \text{ Ic} = 2 \text{ mA}, \text{ RL} = 100 \Omega$		200		μS
	Fall Time *2	tf			200		

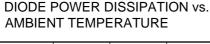
*1 CTR1 = Ic1/IF1, CTR2 = Ic2/IF2

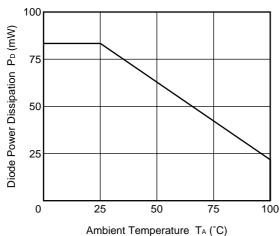


*2 Test circuit for switching time

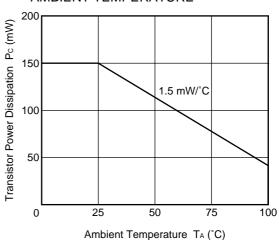


TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

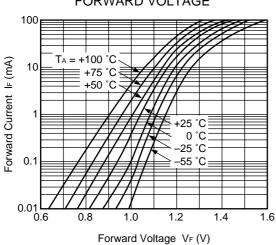




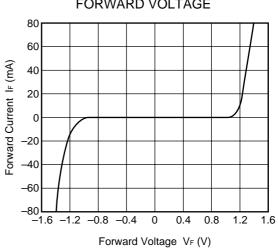
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



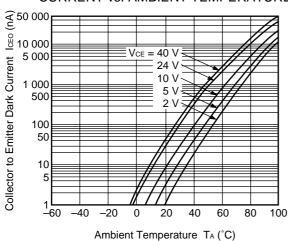
FORWARD CURRENT vs. FORWARD VOLTAGE



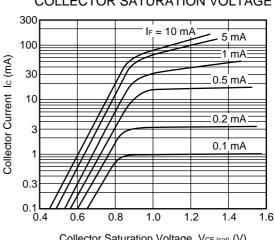
FORWARD CURRENT vs. FORWARD VOLTAGE



COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

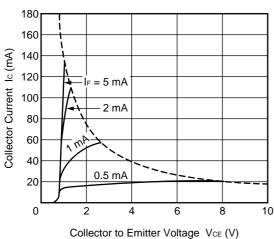


COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**

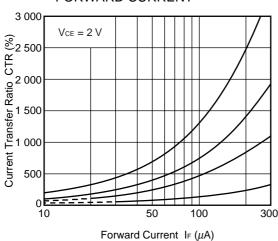


Collector Saturation Voltage VcE (sat) (V)

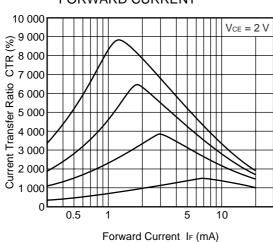
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



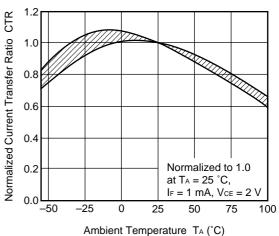
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



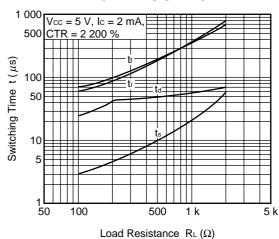
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



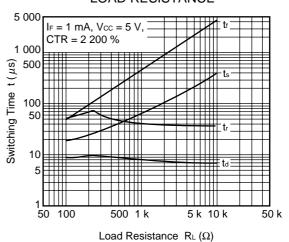
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE

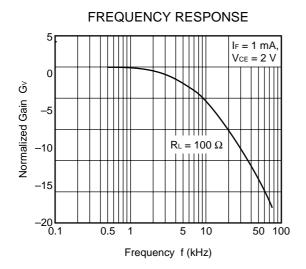


SWITCHING TIME vs. LOAD RESISTANCE

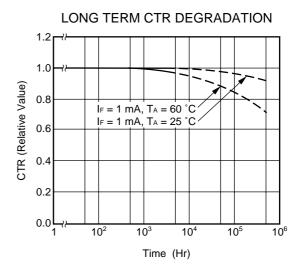


SWITCHING TIME vs. LOAD RESISTANCE

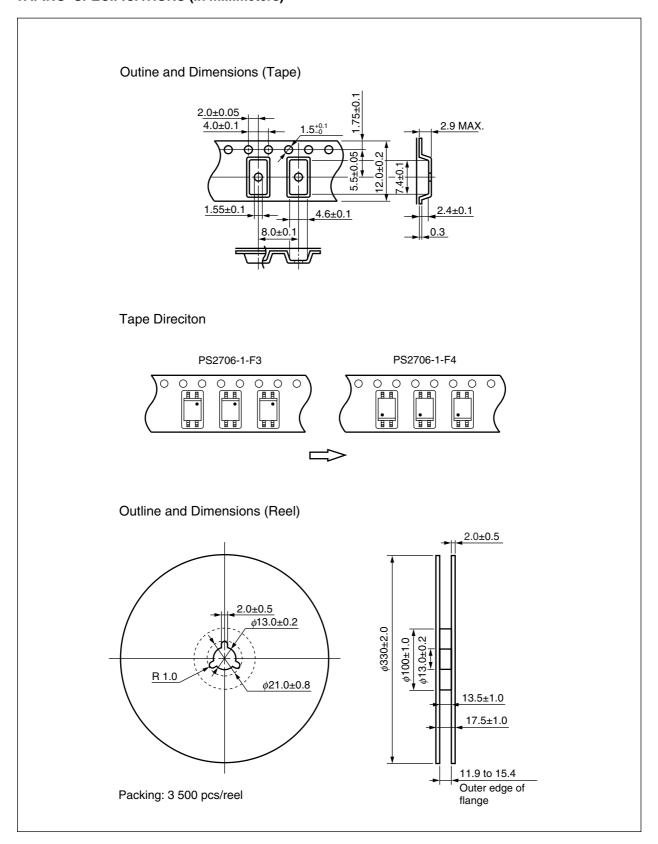




Remark The graphs indicate nominal characteristics.



★ TAPING SPECIFICATIONS (in millimeters)



★ NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

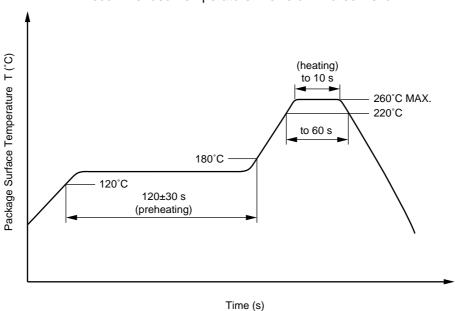
Peak reflow temperature
 260°C or below (package surface temperature)

Time of peak reflow temperature
 Time of temperature higher than 220°C
 60 seconds or less

Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

★ USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

Parameter	Symbol	Speck	Unit
Application classification (DIN VDE 0109) for rated line voltages ≤ 300 Vr.m.s. for rated line voltages ≤ 600 Vr.m.s.		IV III	
Climatic test class (DIN IEC 68 Teil 1/09.80)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.2 \times U_{IORM}$, $P_d < 5 \ pC$	Uiorm Upr	710 850	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices test) $U_{pr}=1.6\times U_{IORM},P_d<5\;pC$	U _{pr}	1 140	V_{peak}
Highest permissible overvoltage	Utr	6 000	V _{peak}
Degree of pollution (DIN VDE 0109)		2	
Clearance distance		> 5	mm
Creepage distance		> 5	mm
Comparative tracking index (DIN IEC 112/VDE 0303 part 1)	СТІ	175	
Material group (DIN VDE 0109)		III a	
Storage temperature range	Tstg	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value VIO = 500 V dc at TA = 25 °C VIO = 500 V dc at TA MAX. at least 100 °C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation)	Tsi Isi Psi	150 200 300	°C mA mW
Isolation resistance Vio = 500 V dc at T _A = 175 °C (Tsi)	Ris MIN.	10 ⁹	Ω

*



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The -AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)		on contained devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.